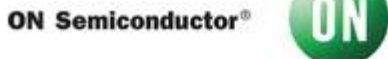

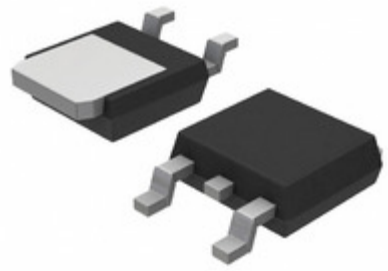


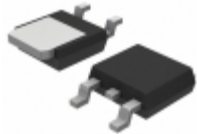




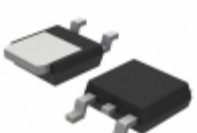
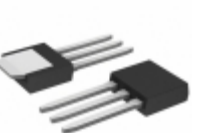
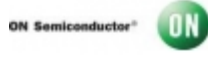
| | |
|---|--|
|  | <h2>NTD5865N-1G</h2> |
| | <p>Hersteller-Teilenummer: NTD5865N-1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 43A DPAK</p> <p>Datenblätter:  NTD5865N-1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
|  | |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|--|--|
| Teilenummer | NTD5865N-1G |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET N-CH 60V 43A DPAK |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 3000 pcs Stock |
| Serie | - |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 175°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-252-3, DPak (2 Leads + Tab), SC-63 |
| Supplier Device-Gehäuse | DPAK-3 |
| Verlustleistung (max) | 71W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 60V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 43A (Tc) |
| Rds On (Max) @ Id, Vgs | 18 mOhm @ 20A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 23nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 1261pF @ 25V |
| Verpackung | Tube |

NTD5865N-1G ist neu im Original, Suche NTD5865N-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD5865N-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD5865N-1G: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|---|---|
|  <p>NTD5862N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 90A DPAK</p> |  <p>NTD5865NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 43A DPAK</p> |  <p>NTD5807NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 23A DPAK</p> |  <p>NTD5807NG O NTD5807NG O</p> |
|  <p>NTD5862N ON NTD5862N ON</p> |  <p>NTD5862NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 98A DPAK</p> |  <p>NTD5865NL-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 46A IPAK</p> |  <p>NTD5867N AMI Semiconductor / ON Semiconductor NTD5867N ON</p> |

heiße Teile

Mehr

| | | | | |
|--|---|--|--|--|
|  NTD5407NT4G |  NTD5412NT4G |  NTD5413N |  D NTD5413NT4G |  NTD5414N |
|  NTD5414NT4G |  NTD5426NT4G |  D NTD5802N |  NTD5802NT4G |  NTD5803N |
|  NTD5803NT4G |  NTD5804N |  NTD5804NG |  NTD5804NT4G |  NTD5805N |
|  D NTD5805NG |  NTD5805NT4G |  NTD5806N |  NTD5806NG |  NTD5806NT4G |
|  NTD5807N |  NTD5807NG |  NTD5807NT4G |  NTD5862N |  NTD5862NT4G |
|  NTD5865NL |  NTD5865NL-1G |  D NTD5865NLT4G |  NTD5865NT4G |  NTD5867NL |
|  NTD5867NL-1G |  D NTD5867NLG |  NTD5867NLT4G |  NTD5867NT4G |  NTD60N02KG |
|  NTD60N02R |  NTD60N02R-001 |  NTD60N02R-032 |  NTD60N02R-035 |  NTD60N02R-1G |
|  NTD60N02R-1R |  NTD60N02R-35G |  NTD60N02RG |  D NTD60N02RG-1G |  NTD60N02RT |
|  NTD60N02RT4 |  NTD60N02RT4G |  NTD60N03RT4G |  NTD60N03T4 |  NTD60N03T4G |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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